



25V PNP LOWSAT TRANSISTOR IN PowerDI3333-8

Features

- BVcEo > -25V
- Small Form Factor Thermally Efficient Package.
 Enables Higher Density End Products
- Ic = -3A High Continuous Current
- Icm = -8A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -200mV @ -1A
- Complementary NPN Type: DXTN07025BFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTP07025BFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208 (©3)
- Weight: 0.03 grams (Approximate)

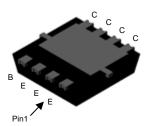
Applications

- High-Side Switch
- Low Drop Out Regulator
- MOSFET or IGBT Gate Driving

PowerDI3333-8 (SWP) (Type UX)

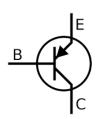


Top View



Bottom View

Equivalent Circuit



Device Symbol

Ordering Information (Note 4)

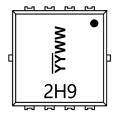
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXTP07025BFGQ-7	Automotive	2H9	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2H9= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 21 = 2021)

WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-35	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	lc	-3	Α
Peak Pulse Current	Ісм	-8	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1.1	W
Power Dissipation	(Note 6)	PD	2.3	W
	(Note 7)		3.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8	ReJL	8.5	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

ESD Ratings (Note 9)

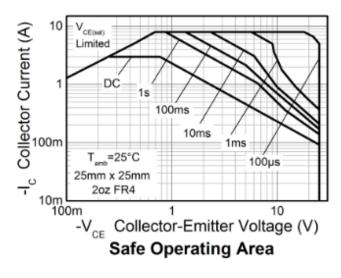
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

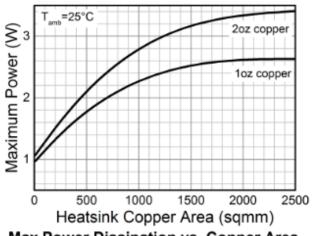
Notes:

- For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
 Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
 Thermal resistance from junction to solder-point (at the collector tab).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

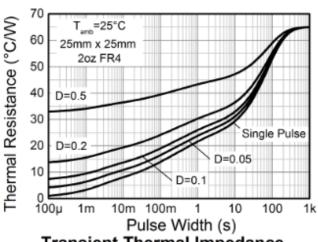


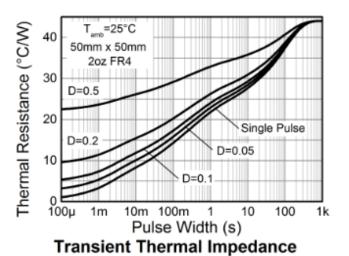
Thermal Characteristics and Derating Information



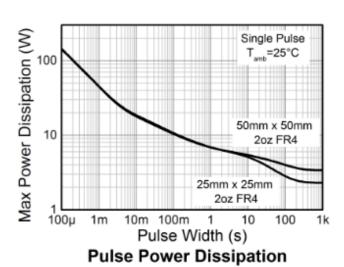


Max Power Dissipation vs. Copper Area





Transient Thermal Impedance



3.5 Max Power Dissipation (W) 50mm x 50mm 3.0 2oz FR4 2.5 2.0 25mm x 25mm 2oz FR4 MRP FR4-PCB 0.5 0.0 100 125 0 25 150 Temperature (°C)

Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

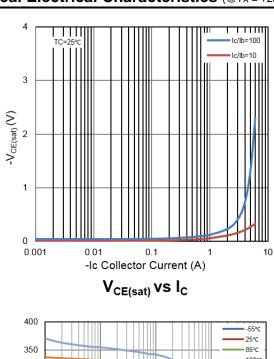
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-35	-71	_	V	Ic = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-25	-42	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.3	_	V	$I_E = -100 \mu A$
Collector Cut-Off Current	lana	1	1	-20	nA	VcB = -30V
Conector Cut-On Current	Ісво	1	1	-10	μA	V _{CB} = -30V, T _A = +125°C
Emitter Cut-Off Current	IEBO	_	_	-20	nA	VEB = -6V
Collector Emitter Seturation Voltage (Note 10)	\/·	_	-64	-200	mV	Ic = -1A, I _B = -100mA
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	1	-164	-400	mV	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-0.86	-1	V	Ic = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	1	-0.77	-0.9	V	Ic = -1A, VcE = -2V
	hFE	70	196	_	_	Ic = -50mA, VcE = -2V
DC Current Coin (Note 10)		100	174	300	_	$I_C = -1A$, $V_{CE} = -2V$
DC Current Gain (Note 10)		75	153	_	_	$I_C = -2A$, $V_{CE} = -2V$
		40	94	_	_	Ic = -6A, VcE = -2V
Current Gain-Bandwidth Product	fτ	100	160	_	MHz	V _{CE} = -5V, I _C = -100mA f = 100MHz
Turn-On Time	ton	_	40	_	ns	Vcc = -10V, Ic = -500mA
Turn-Off Time	t _{off}	_	450	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Output Capacitance	C _{obo}	_	55	100	pF	V _{CB} = -10V, f = 1MHz

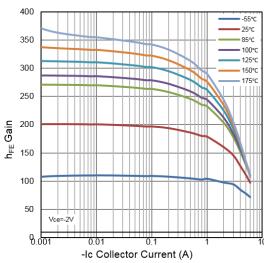
Note:

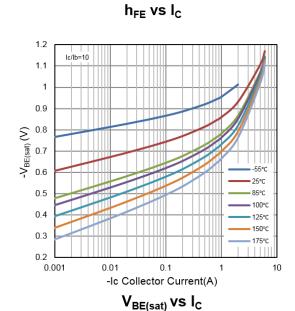
10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

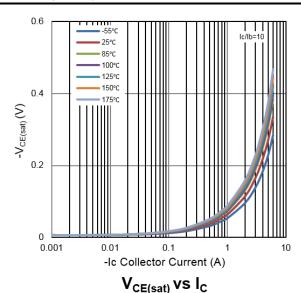


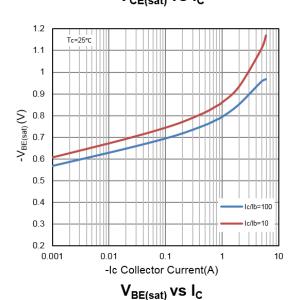
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

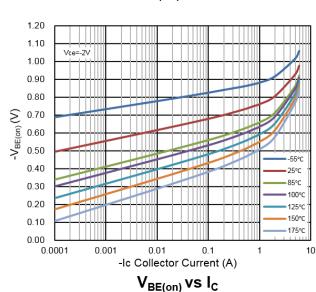










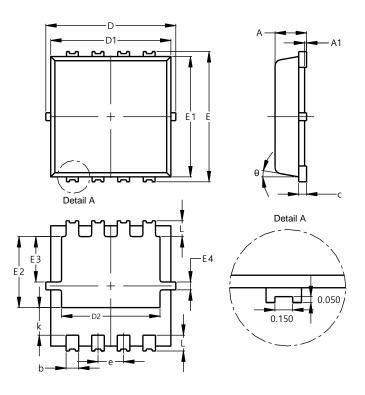




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

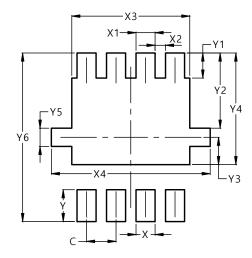


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
C	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
e	_	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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